# 74HC594-Q100; 74HCT594-Q100

# 8-bit shift register with output register

Rev. 1 — 2 August 2012

**Product data sheet** 

## 1. General description

The 74HC594-Q100; 74HCT594-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC594-Q100; 74HCT594-Q100 is an 8-bit, non-inverting, serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Separate clocks (SHCP and STCP) and direct overriding clears (SHR and STR) are provided on both the shift and storage registers. A serial output (Q7S) is provided for cascading purposes.

Both the shift and storage register clocks are positive-edge triggered. If both clocks are connected together, the shift register is always one count pulse ahead of the storage register.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Synchronous serial input and output
- Complies with JEDEC standard No.7A
- 8-bit parallel output
- Shift and storage registers have independent direct clear and clocks
- Independent clocks for shift and storage registers
- 100 MHz (typical)
- Multiple package options
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

## 3. Applications

- Serial-to parallel data conversion
- Remote control holding register

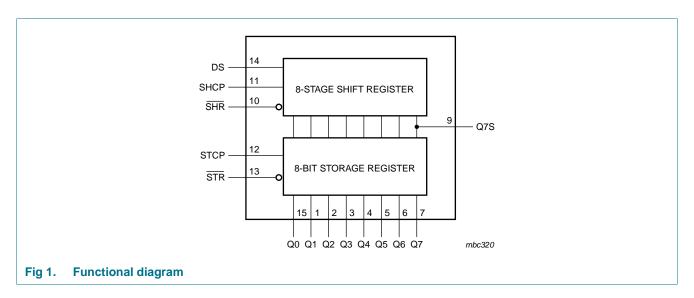


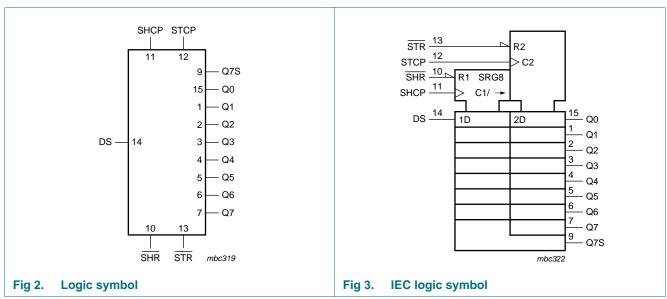
## 4. Ordering information

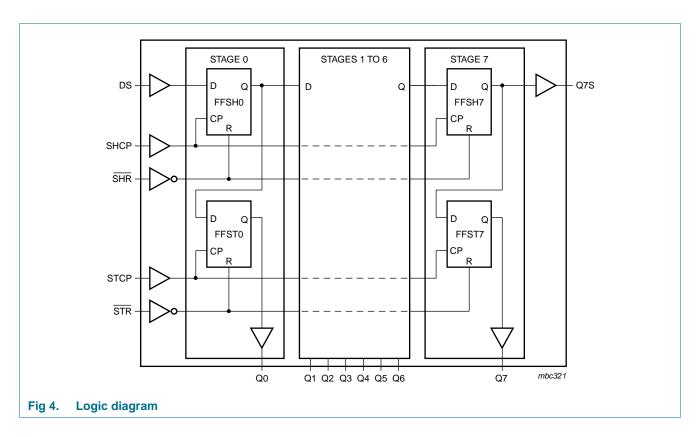
Table 1. Ordering information

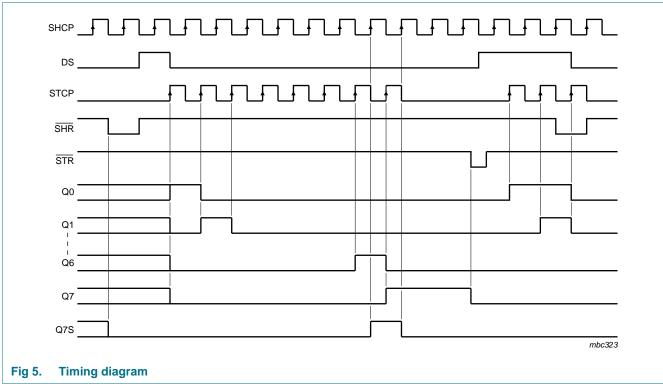
Type number	Package							
	Temperature range	Name	Description	Version				
74HC594D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1				
74HCT594D-Q100			body width 3.9 mm					

## 5. Functional diagram



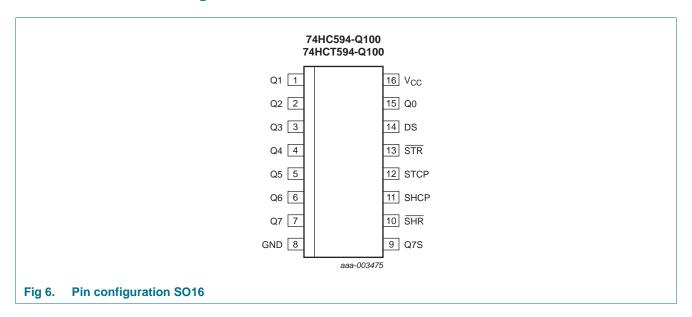






## 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
SHR	10	shift register reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
STR	13	storage register reset (active LOW)
DS	14	serial data input
V <sub>CC</sub>	16	supply voltage

## 7. Functional description

Table 3. Function table[1]

Function	Input					
	SHR	STR	SHCP	STCP	DS	
Clear shift register	L	Χ	X	Χ	X	
Clear storage register	Χ	L	X	Χ	X	
Load DS into shift register stage 0, advance previous stage data to the next stage	Н	Χ	<b>↑</b>	Χ	H or L	
Transfer shift register data to storage register and outputs Qn	Χ	Н	X	<b>↑</b>	X	
Shift register one count pulse ahead of storage register	Н	Н	$\uparrow$	$\uparrow$	X	

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level;  $L = LOW \text$ 

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					-
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$V_O = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$			
		Serial data output Q7S	-	±25	mA
		Parallel data output	-	±35	mA
I <sub>CC</sub>	supply current	Serial data output Q7S	-	50	mA
		Parallel data output	-	70	mA
$I_{GND}$	ground current	Serial data output Q7S	-	-50	mA
		Parallel data output	-	-70	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] _	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For SO16 packages: above 70  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

## 9. Recommended operating conditions

Table 5. Recommended operating conditions

Table 5.	Recommended operating co					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74HC	C594-Q100					
$V_{CC}$	supply voltage		2.0	5.0	6.0	V
V <sub>I</sub>	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
t <sub>r</sub>	rise time	$V_{CC} = 2.0 \text{ V}$	-	-	1000	ns
		$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	400	ns
t <sub>f</sub>	fall time	$V_{CC} = 2.0 \text{ V}$	-	-	1000	ns
		V <sub>CC</sub> = 4.5 V	-	6.0	500	ns
		V <sub>CC</sub> = 6.0 V	-	-	400	ns
Type 74H0	CT594-Q100					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
t <sub>r</sub>	rise time	$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns
t <sub>f</sub>	fall time	$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns

### 10. Static characteristics

Table 6. Static characteristics type 74HC594-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V

74HC\_HCT594\_Q100

 Table 6.
 Static characteristics type 74HC594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
		Parallel data outputs				
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	μА
Ci	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -40	0 °C to +85 °C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_O = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
		Parallel data outputs				
		$I_O = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_O = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
		Parallel data outputs				
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	80	μА

 Table 6.
 Static characteristics type 74HC594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
$T_{amb} = -40$	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
		Parallel data outputs				
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	160	μА

Table 7. Static characteristics type 74HCT594-Q100

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_O = 4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		Parallel data outputs				
		$I_{O} = 6.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	-	0.16	0.26	V
<u>.</u>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 4.5 \text{ V}$ to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	150	540	μΑ
		pin DS	-	25	90	μΑ
C <sub>i</sub>	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -40	0 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output				
		$I_O = 4.0$ mA; $V_{CC} = 4.5$ V	-	-	0.33	V
		Parallel data outputs				
		$I_{O}$ = 6.0 mA; $V_{CC}$ = 4.5 V	-	-	0.33	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	80	μΑ

Table 7. Static characteristics type 74HCT594-Q100 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 4.5 \text{ V}$ to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	-	675	μΑ
		pin DS	-	-	112.5	μΑ
$T_{amb} = -40$	0 °C to +125 °C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		Parallel data outputs				
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		Serial data output Q7S				
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		Parallel data outputs				
		$I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	160	μА
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 4.5 \text{ V}$ to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	-	735	μΑ
		pin DS	-	-	122.5	μΑ

## 11. Dynamic characteristics

Table 8. Dynamic characteristics type 74HC594-Q100

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see } Figure 13.$ 

Note	Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to +125 °C		Unit	
The color of the				Min	Тур	Max	Min	Max	Min	Max		
Voc = 4.5 V	<sup>t</sup> pd			1						'	'	
Voc = 5.0 V;			$V_{CC} = 2.0 \text{ V}$	-	44	150	-	185	-	225	ns	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			$V_{CC} = 4.5 \text{ V}$	-	16	30	-	37	-	45	ns	
STCP to Qn; see Figure 8				-	13	-	-	-	-	-	ns	
Figure 8   V <sub>CC</sub> = 2.0 V			$V_{CC} = 6.0 \text{ V}$	-	14	26	-	31	-	38	ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$												
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			$V_{CC} = 2.0 \text{ V}$	-	44	150	-	185	-	225	ns	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			$V_{CC} = 4.5 \text{ V}$	-	16	30	-	37	-	45	ns	
HIGH to LOW propagation delay  HIGH to LOW propagation delay  Figure 11  Vcc = 2.0 V				-	13	-	-	-	-	-	ns	
LOW propagation delay    Voc = 2.0 V			$V_{CC} = 6.0 \text{ V}$	-	14	26	-	31	-	38	ns	
Allelay   Variable	t <sub>PHL</sub>	LOW propagation										
$V_{CC} = 4.5  \text{V} \qquad - \qquad 14 \qquad 30 \qquad - \qquad 37 \qquad - \qquad 45$ $V_{CC} = 5.0  \text{V}; \qquad - \qquad 11 \qquad - \qquad $			$V_{CC} = 2.0 \text{ V}$	-	39	150	-	185	-	225	ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		uelay	$V_{CC} = 4.5 \text{ V}$	-	14	30	-	37	-	45	ns	
$ \frac{\text{STR to Qn; see}}{\text{Figure 12}}                                  $				-	11	-	-	-	-	-	ns	
			$V_{CC} = 6.0 \text{ V}$	-	12	26	-	31	-	38	ns	
$V_{CC} = 4.5 \text{ V} \qquad - \qquad 14 \qquad 25 \qquad - \qquad 31 \qquad - \qquad 37$ $V_{CC} = 5.0 \text{ V}; \qquad - \qquad 11 \qquad - \qquad $												
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			$V_{CC} = 2.0 \text{ V}$	-	39	125	-	155	-	185	ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			$V_{CC} = 4.5 \text{ V}$	-	14	25	-	31	-	37	ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$				-	11	-	-	-	-	-	ns	
LOW output transition time			$V_{CC} = 6.0 \text{ V}$	-	12	21	-	26	-	31	ns	
transition time	THL		see Figure 7									
time $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			Serial data output G	Q7S								
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			$V_{CC} = 2.0 \text{ V}$	-	19	75	-	95	-	110	ns	
Parallel data outputs $V_{CC} = 2.0 \text{ V}$ -       14       60       -       75       -       90 $V_{CC} = 4.5 \text{ V}$ -       5       12       -       15       -       18			$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns	
V <sub>CC</sub> = 2.0 V       -       14       60       -       75       -       90         V <sub>CC</sub> = 4.5 V       -       5       12       -       15       -       18			$V_{CC} = 6.0 \text{ V}$	-	6	13	-	16	-	19	ns	
V <sub>CC</sub> = 4.5 V - 5 12 - 15 - 18			Parallel data output	s								
			$V_{CC} = 2.0 \text{ V}$	-	14	60	-	75	-	90	ns	
V <sub>CC</sub> = 6.0 V - 4 10 - 13 - 15			$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns	
		$V_{CC} = 6.0 \text{ V}$	-	4	10	-	13	-	15	ns		

74HC\_HCT594\_Q100

 Table 8.
 Dynamic characteristics type 74HC594-Q100 ...continued

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see Figure 13.}$ 

Symbol	Parameter	Conditions		25 °C		-40 °C to	–40 °C to +85 °C		-40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
TLH	LOW to	see Figure 7		'				•		
	HIGH output transition	Serial data output Q7	S							
	time	$V_{CC} = 2.0 \text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$	-	6	13	-	16	-	19	ns
		Parallel data outputs								
		$V_{CC} = 2.0 \text{ V}$	-	14	60	-	75	-	90	ns
		$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns
r		$V_{CC} = 6.0 \text{ V}$	-	4	10	-	13	-	15	ns
t <sub>W</sub>	pulse width	SHCP (HIGH or LOW); see Figure 7								
		$V_{CC} = 2.0 \text{ V}$	80	10	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$	16	4	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$	14	3	-	17	-	20	-	ns
		STCP (HIGH or LOW); see Figure 8								
		$V_{CC} = 2.0 \text{ V}$	80	10	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$	16	4	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$	14	3	-	17	-	20	-	ns
	SHR and STR (HIGH or LOW); see Figure 11 and Figure 12									
		$V_{CC} = 2.0 \text{ V}$	80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$	16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$	14	4	-	17	-	20	-	ns

Table 8. Dynamic characteristics type 74HC594-Q100 ...continued

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see Figure 13.}$ 

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Uni
			Min	Тур	Max	Min	Max	Min	Max	
su	set-up time	DS to SHCP; see <u>Figure 9</u>	'		'	1				
		$V_{CC} = 2.0 \text{ V}$	100	10	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	4	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	3	-	21	-	26	-	ns
		SHR to STCP; see Figure 10								
		$V_{CC} = 2.0 \text{ V}$	100	14	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$	20	5	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$	17	4	-	21	-	26	-	ns
		SHCP to STCP; see Figure 8								
		$V_{CC} = 2.0 \text{ V}$	100	17	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$	20	6	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$	17	5	-	21	-	26	-	ns
t <sub>h</sub> hold time	hold time	DS to SHCP; see <u>Figure 9</u>								
		V <sub>CC</sub> = 2.0 V	25	-8	-	30	-	35	-	ns
		$V_{CC} = 4.5 \text{ V}$	5	-3	-	6	-	7	-	ns
		$V_{CC} = 6.0 \text{ V}$	4	-2	-	5	-	6	-	ns
t <sub>rec</sub> recovery time	SHR to SHCP and STR to STCP; see Figure 11 and Figure 12									
		$V_{CC} = 2.0 \text{ V}$	50	-14	-	65	-	75	-	ns
		$V_{CC} = 4.5 \text{ V}$	10	<b>–</b> 5	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}$	9	-4	-	11	-	13	-	ns
111007	maximum frequency	SHCP or STCP; see <u>Figure 7</u> and <u>Figure 8</u>								
		V <sub>CC</sub> = 2.0 V	6.0	30	-	4.8	-	4.0	-	MH
		$V_{CC} = 4.5 \text{ V}$	30	92	-	24	-	20	-	МН
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	100	-	-	-	-	-	МН
		V <sub>CC</sub> = 6.0 V	35	109	-	28	-	24	-	MH

 Table 8.
 Dynamic characteristics type 74HC594-Q100 ...continued

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see } Figure 13.$ 

Symbol	Parameter	Conditions	25 °C -		–40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
$C_{PD}$	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ [2] $V_{CC} = 5 \text{ V};$ $f_i = 1 \text{ MHz}$	-	84	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

Table 9. Dynamic characteristics type 74HCT594-Q100

 $GND = 0 \text{ V; } V_{CC} = 4.5 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see } Figure 13.$ 

Symbol	Parameter	Conditions		25 °C		-40 °C to	-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation delay	SHCP to Q7S; [1] see Figure 7	-	18	32	-	40	-	48	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		STCP to Qn; see Figure 8	-	18	32	-	40	-	48	ns
		$V_{CC} = 5.0 \text{ V};$ $C_{L} = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
LOV prop	HIGH to LOW	SHR to Q7S; see Figure 11	-	17	30	-	38	-	45	ns
	propagation delay	$V_{CC} = 5.0 \text{ V};$ $C_{L} = 15 \text{ pF}$	-	14	-	-	-	-	-	ns
		STR to Qn; see Figure 12	-	17	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V};$ $C_{L} = 15 \text{ pF}$	-	14	-	-	-	-	-	ns
t <sub>THL</sub>	HIGH to	see Figure 7								
	LOW output transition	Serial data output Q7	'S							
	time	$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
		Parallel data outputs								
		$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns
t <sub>TLH</sub>	LOW to	see Figure 7								
	HIGH output	Serial data output Q7	'S							
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
		Parallel data outputs								
		$V_{CC} = 4.5 \text{ V}$	-	5	12	-	15	-	18	ns

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**Table 9. Dynamic characteristics type 74HCT594-Q100** ...continued GND = 0 V;  $V_{CC} = 4.5$  V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>W</sub> pulse w	pulse width	SHCP (HIGH or LOW); see <u>Figure 7</u>	16	4	-	20	-	24	-	ns
		STCP (HIGH or LOW); see Figure 8	16	4	-	20	-	24	-	ns
		SHR and STR (HIGH or LOW); see Figure 11 and Figure 12	16	6	-	20	-	24	-	ns
t <sub>su</sub> set-up time	set-up time	DS to SHCP; see <u>Figure 9</u>	20	4	-	25	-	30	-	ns
		SHR to STCP; see Figure 10	20	6	-	25	-	30	-	ns
		SHCP to STCP; see Figure 8	20	7	-	25	-	30	-	ns
t <sub>h</sub>	hold time	DS to SHCP; see <u>Figure 9</u>	5	-3	-	6	-	7	-	ns
t <sub>rec</sub>	recovery time	SHR to SHCP and STR to STCP; see Figure 11 and Figure 12	10	<b>–</b> 5	-	13	-	15	-	ns
f <sub>max</sub> maximum frequency	SHCP or STCP; see <u>Figure 7</u> and <u>Figure 8</u>	30	92	-	24	-	20	-	MHz	
		$V_{CC} = 5.0 \text{ V};$ $C_{L} = 15 \text{ pF}$	-	100	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_I$ = GND to $V_{CC}$ - 1.5 V; $V_{CC}$ = 5 V; $f_i$ = 1 MHz	[2] -	89	-	-	-	-	-	pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

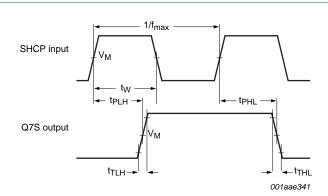
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 12. Waveforms

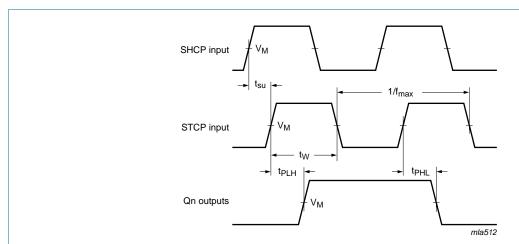


Measurement points are given in Table 10.

 $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

 $t_{TLH}$  = LOW to HIGH output transition time;  $t_{THL}$  = HIGH to LOW output transition time.

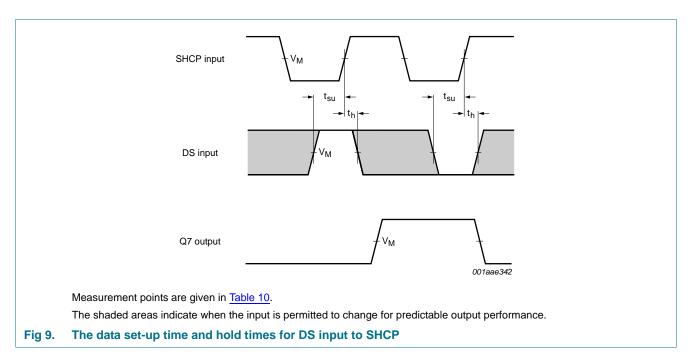
Fig 7. The shift clock (SHCP) to output (Q7S) propagation delays, the shift clock pulse width, the maximum shift clock frequency, and output transition times

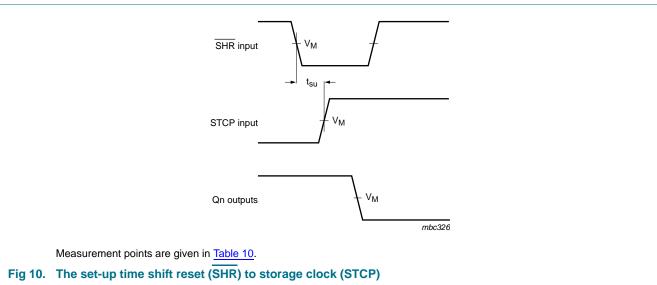


Measurement points are given in Table 10.

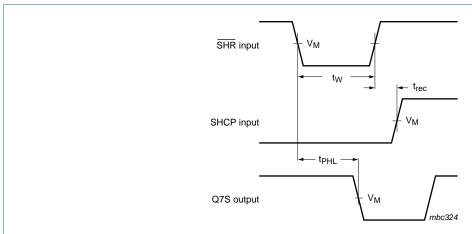
 $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{pd}}$ .

Fig 8. The storage clock (STCP) to output (Qn), propagation delays, the storage clock pulse width, the maximum storage clock pulse frequency and the shift clock to storage clock set-up time





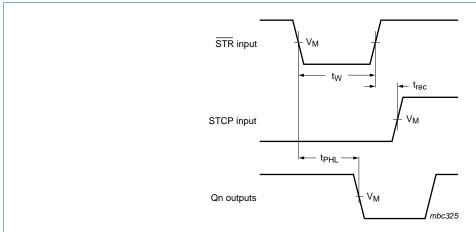
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Measurement points are given in  $\underline{\text{Table 10}}$ .

t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Fig 11. The shift reset (SHR) pulse width, the shift reset to output (Q7S) propagation delay and the shift reset to shift clock (SHCP) recovery time



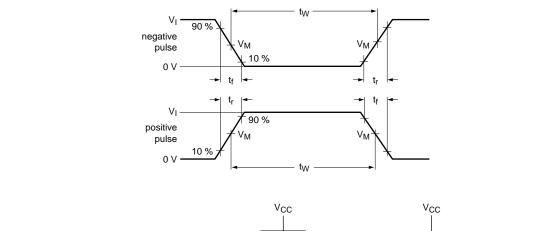
Measurement points are given in Table 10.

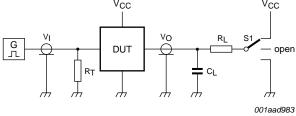
 $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{pd}}$ .

Fig 12. The storage reset (STR) pulse width, the storage reset to output (Qn) propagation delay and the storage reset to storage clock (STCP) recovery time

Table 10. Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC594-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT594-Q100	1.3 V	1.3 V





Test data is given in Table 11.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator

 $C_L$  = Load capacitance including jig and probe capacitance

R<sub>I</sub> = Load resistor

S1 = Test selection switch

Fig 13. Test circuit for measuring switching times

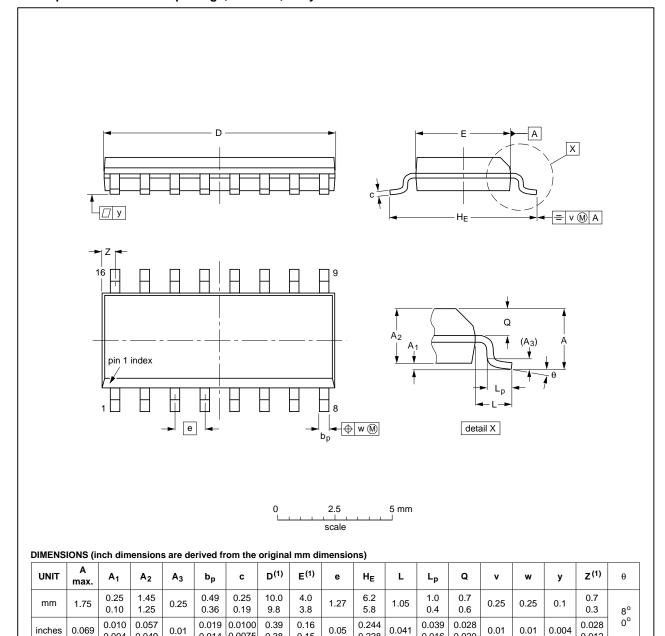
Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC594-Q100	$V_{CC}$	6 ns	15 pF, 50 pF	1 kΩ	open	GND	$V_{CC}$
74HCT594-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

## 13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 0.0075

0.38

0.15

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19

0.228

0.020

Fig 14. Package outline SOT109-1 (SO16)

0.004

0.049

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## 14. Abbreviations

### Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
LSTTL	Low-Power Schottky Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

## 15. Revision history

### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT594_Q100 v.1	20120802	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# 74HC594-Q100; 74HCT594-Q100

### **NXP Semiconductors**

8-bit shift register with output register

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